

TECHNICAL DATA
DATA SHEET 956, REV. C**HERMETIC POWER SCHOTTKY RECTIFIER**
Very Low Forward Voltage Drop**Applications:**

- Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Reverse Leakage Current
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Add a "C" after the SHD for ceramic seals (SHDC125446)

Maximum Ratings:

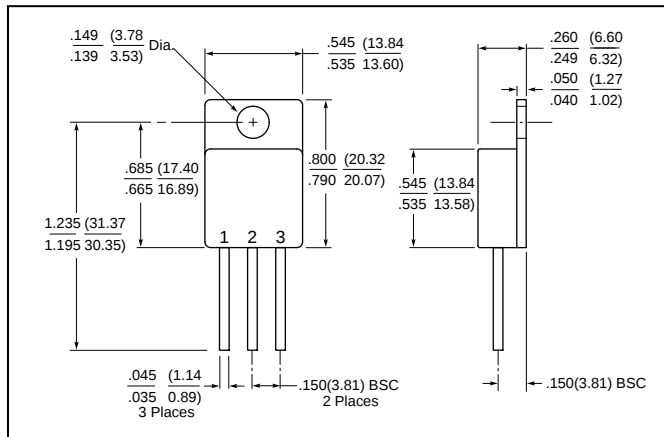
Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	200	V
Max. Average Forward Current Common Cathode / Anode	$I_{F(AV)}$	50% duty cycle, rectangular wave form	30	A
Max. Average Forward Current Single / Doubler	$I_{F(AV)}$	50% duty cycle, rectangular wave form	15	A
Max. Peak One Cycle Surge Current Non-Repetitive per leg	I_{FSM}	8.3 ms, half Sine wave (per leg)	200	A
Non-Repetitive Avalanche Energy per leg	E_{AS}	$T_J = 25\text{ }^{\circ}\text{C}$, $I_{AS} = 0.75\text{ A}$, $L = 40\text{ mH}$	16	mJ
Repetitive Avalanche Current per leg	I_{AR}	I_{AS} decay linearly to 0 in $1\text{ }\mu\text{s}$ f limited by T_J max $V_A = 1.5V_R$	0.75	A
Thermal Resistance (per leg)	$R_{\theta JC}$	-	1.5	$^{\circ}\text{C/W}$
Max. Junction Temperature	T_J	-	-65 to +200	$^{\circ}\text{C}$
Max. Storage Temperature	T_{stg}	-	-65 to +175	$^{\circ}\text{C}$

Electrical Characteristics:

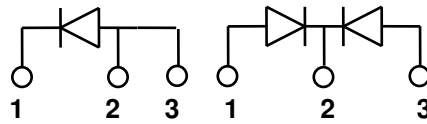
Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg)	V_{F1}	@ 30A, Pulse, $T_J = 25\text{ }^{\circ}\text{C}$	1.09	V
	V_{F2}	@ 30A, Pulse, $T_J = 125\text{ }^{\circ}\text{C}$	0.93	V
Max. Reverse Current (per leg)	I_{R1}	@ $V_R = 200\text{ V}$, Pulse, $T_J = 25\text{ }^{\circ}\text{C}$	0.7	mA
	I_{R2}	@ $V_R = 200\text{ V}$, Pulse, $T_J = 125\text{ }^{\circ}\text{C}$	16	mA
Max. Junction Capacitance (per leg)	C_T	@ $V_R = 5\text{ V}$, $T_C = 25\text{ }^{\circ}\text{C}$ $f_{SIG} = 1\text{ MHz}$, $V_{SIG} = 50\text{ mV (p-p)}$	600	pF
Max. Reverse Recovery Time	t_{rr}	$I_F = 0.5\text{ A}$, $I_R = 1.0\text{ A}$, $I_{RM} = 0.25\text{ A}$, $T_J = 25\text{ }^{\circ}\text{C}$	50	nsec

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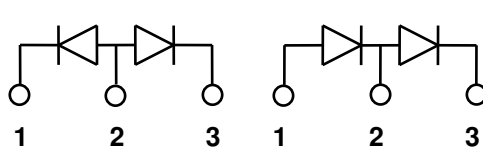
Mechanical Dimensions: In Inches / mm



SINGLE COMMON CATHODE



COMMON ANODE DOUBLER



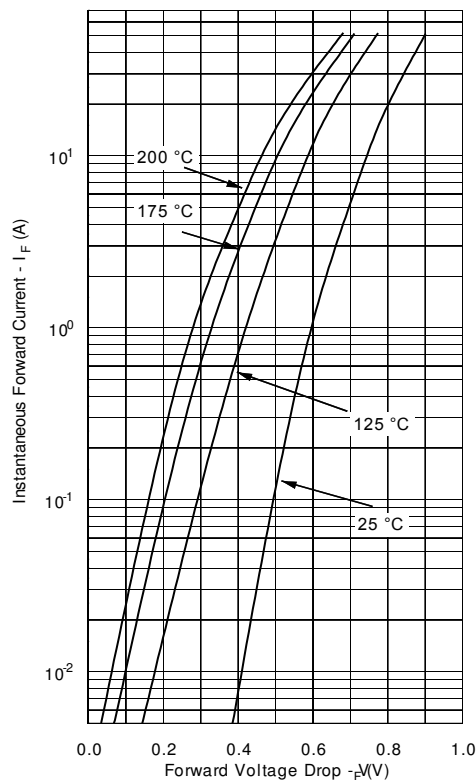
TO-254

PINOUT TABLE

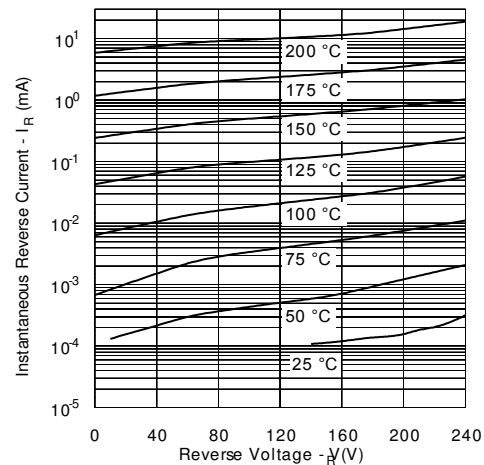
TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
DUAL RECTIFIER, COMMON CATHODE (P)	ANODE 1	COMMON CATHODE	ANODE 2
DUAL RECTIFIER, COMMON ANODE (N)	CATHODE 1	COMMON ANODE	CATHODE 2
DUAL RECTIFIER, DOUBLER (D)	ANODE	CATHODE/ ANODE	CATHODE

Curves shown are for bare die only.

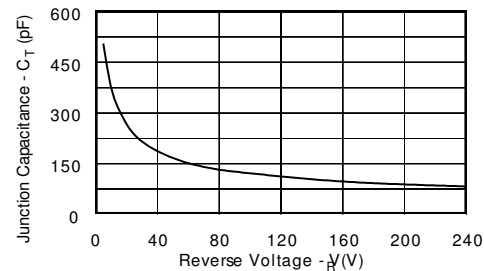
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



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